NSN 5961-00-841-8941

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-841-8941 **Inclosure Material:** Metal **Overall Length:** 0.359 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0